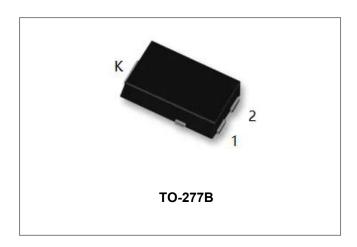




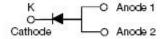
ST8100S SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- "-A" is an AEC-Q101 qualified device
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T∟=125°C, rectangular wave form	8	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _J = 25 °C	150	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 4A, Pulse, T _J = 25 °C @ 8A, Pulse, T _J = 25 °C	0.52 0.66	- 0.68	V
	V_{F2}	@ 4A, Pulse, T _J = 125 °C @ 8A, Pulse, T _J = 125 °C	0.47 0.58	- 0.62	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	13.5	70	uA
Reverse Current*	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	3.5	15	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C} \\ f_{SIG} = 1MHz$	542	-	pF

^{*} Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •

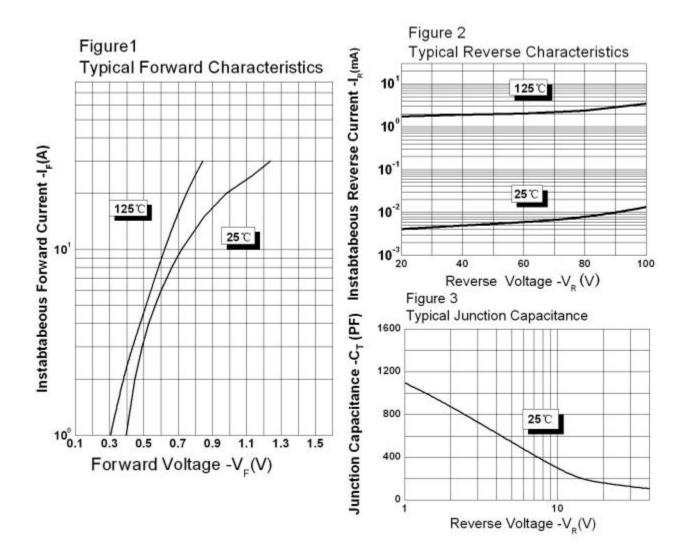




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

Ratings and Characteristics Curves

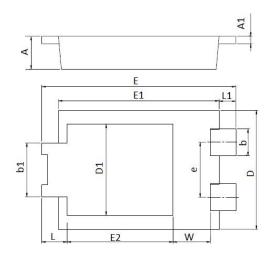


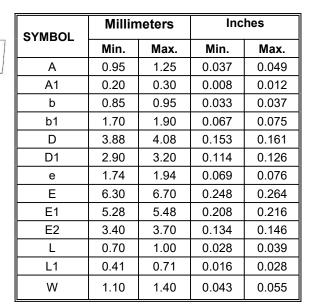
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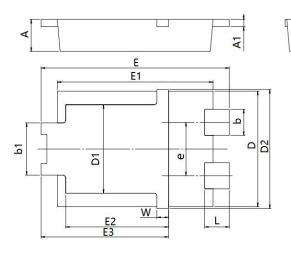


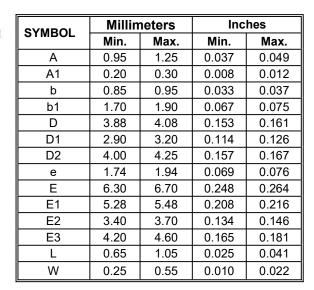
Mechanical Dimensions TO-277B





Mechanical Dimensions TO-277B(New)





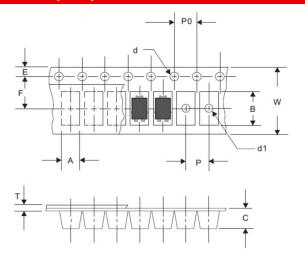
Notes: New Mechanical Dimensions is performed from date code 2236X.

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Carrier Tape Specification TO-277B



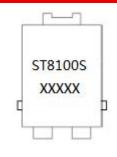
SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

Ordering Information

Device	Package	Shipping
ST8100S	TO-277B(Pb-Free)	5000pcs/ reel
ST8100STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 ST
 = Device Type

 8
 = Forward Current (8A)

 100
 = Reverse Voltage (100V)

 S
 = Package type

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

DISCLAIMER:

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- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
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